FEB 2 8 2006 & SHEET 1 OF 1

Form PTO 1449 (Modified)		U.S. DEPARTMENT PATENT AND TRA	OF COMMERCE DEMARK OFFICE	ATTY DOCKET NO. 280759USOPCT	8	SERIAL		
,				280759USOPCT CATRADE		10/558,	621	
LISTO	DEEE	RENCES CITED BY AF	DITCANT	AFFLICANI				
LISTOF	KEFE	NENCES CITED BY AF	PLICANI	Hubert MORICEAU, et al.				
				FILING DATE		GROUP		
				November 28, 2005		2817		
U.S. PATENT DOCUMENTS								
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE	
SDI	AA	6 246 068	06/12/01	Nobuhiko SATO et al.				
	AB	6 569 748	05/27/03	Nobuhiko SATO et al.				
	AC	2002/19118	02/14/02	Chung CHAN				
	AD	6 335 258	01/01/02	Bernard ASPAR et al.				
	AE	5 953 622	09/14/99	Sahng Kyoo LEE et al.			1	
	AF					7		
	AG				·		Χ	
	AH							
	M		<u> </u>			/	\	
\	N N			\sim			\	
	AK					$\overline{}$		
	AL		 					
	AM				-/-			
	AN		 					
FOREIGN PATENT DOCUMENTS								
	,		1		-			
\times		DOCUMENT NUMBER	DATE	COUNTRY		YES	TRANSLATION NO	
BOI	ÃO	00/48278	08/17/00	WO(equivalent of US 2004/175901)			NO	
	AB					1	7 \ 7	
	AQ							
	AR		1			X		
	AS						X	
	AT							
	AY							
	AV \							
OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, etc.)								
SDI	M. BRUEL, "Silicon on insulator material technology", ELECTRONICS LETTERS, vol. 31, no. 14, pages 1201-1202 07/06/95							
								
	AX							
AY								
	AZ			·	☐ Addii	ional Pofo	rancas chaol(a) attact ad	
/	┸┲┦		7		Additional References sheet(s) attached			
Examiner	mette d		Date Considered 3/22/07					
*Examiner: Initial if reference is considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant								